

Semismitted herewith for filing is the Patent Application of:

Inventor: YISUO LI, FRANCIS BENISTANT, KIM HYUN SIK, ZHAO LUN

Request & Certification under 35 USC 122(b)(2)(b)(i)

STABILITY

SHALLOW LOW ENERGY ION IMPLANTATION INTO PAD OXIDE FOR IMPROVING THRESHOLD VOLTAGE

Enclose	d are:				
x	3 sheets of drawing(s) - formal.				
x	An assignment of the invention to Chartered Semiconductor Manufacturing Ltd.				
	An associate power of attorney Applicant claims small entity status				

The filing fee has been calculated as shown below:

	(Col. 1)	(Col. 2)	OTHER THAN	A SMALL ENTITY
FOR:	NO. FILED	NO. EXTRA	RATE	FEE
BASIC FEE	><	><		\$ 770.
TOTAL CLAIMS	16 -20=	0	x 18 =	\$ 0.
INDEP CLAIMS	3 -3=	0	x 86 =	\$ 0.
			UB TOTAL	\$ 770.
			SSIGNMENT	\$40.
		T	OTAL	\$ 810.

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X Any additional filing fees required under 37 CFR §1.16.

X Any patent application processing fees under 37 CFR §1.17.

Respectfully submitted,
STEPHEN B. ACKERMAN, REG. NO. 37,761

EXPRESS MAIL CERTIFICATE

Express Mail No.EV385358770US

I hereby certify that this correspondence is being deposited with the United States Postal Service as Express Mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA, 22313-1450. Applicant and/or Attorney requests the date of deposit as the Filing Date.

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